

Switch-mode Power Rectifiers NHPV08S600G

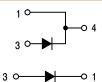
Features

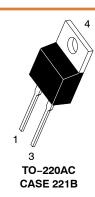
- Ultrafast 30 Nanosecond Recovery Time
- 150°C Operating Junction Temperature
- High Voltage Capability of 600 V
- Low Forward Drop
- Low Leakage Specified @ 125°C Case Temperature
- This Device is Pb-Free and RoHS Compliant

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

PLANAR ULTRAFAST RECTIFIERS 8 A, 600 V





MARKING DIAGRAMS



A = Assembly Location

Y = Year WW = Work Week

G = Pb-Free Package KA = Diode Polarity

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|-----------------------|-----------------|
| NHPV08S600G | TO-220AC (Pb-Free) | 50 Units / Rail |

^{*}For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NHPV08S600G

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|--|------------------------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 600 | V |
| Average Rectified Forward Current (Rated V _R) | I _{F(AV)} | 8 A @ T _C = 130°C | Α |
| Peak Rectified Forward Current (Rated V _R , Square Wave, 20 kHz) | I _{FRM} | 8 A @ T _C = 125°C | Α |
| Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | I _{FSM} | 80 | А |
| Operating Junction Temperature and Storage Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Value | Unit |
|---|----------------|-------|------|
| NHPV08S600G: Thermal Resistance Junction-to-Case (Note 1) | $R_{	heta JC}$ | 1.5 | °C/W |
| NHPJ08S600G: Thermal Resistance Junction-to-Case (Note 1) | | 4.25 | °C/W |

^{1.} Junction–to–Case shown as a typical value using a fixed 25°C cold plate boundary.

ELECTRICAL CHARACTERISTICS

| Characteristic | Test Conditions | Symbol | Тур | Max | Unit |
|---|---|--|--------------------------|--------------------|--------------------|
| Instantaneous Forward Voltage (Note 2) | (I _F = 8 A, T _C = 125°C) (I _F = 8 A, T _C = 25°C) | V _F | 1.5 2.7 | 1.8 3.2 | V |
| Instantaneous Reverse Current (Note 2) | (Rated DC Voltage, T _C = 125°C) (Rated DC Voltage, T _C = 25°C) | I _R | 46 0.1 | 400 30 | μΑ |
| Reverse Recovery Time | $(I_F = 0.5 \text{ A}, I_{rr} = 0.25 \text{ A}, I_R = 1 \text{ A})$ $(I_F = 1 \text{ A}, dI_F/dt = -50 \text{ A}/\mu\text{s}, V_R = 30 \text{ V})$ | t _{rr} | - - | 30 50 | ns |
| Reverse Recovery Time Peak Reverse Recovery Current Total Reverse Recovery Charge Softness Factor | $(I_F = 8 \text{ A}, d_{IF}/d_t = -200 \text{ A}/\mu s, T_C = 25^{\circ}\text{C})$ | t _{rr} I _{RM} Q _{rr} S | 30 2.3 37 2 | 50 3 50 - | ns A nC - |
| Reverse Recovery Time Peak Reverse Recovery Current Total Reverse Recovery Charge Softness Factor | $(I_F = 8 \text{ A}, d_{IF}/d_t = -200 \text{ A/}\mu\text{s}, T_C = 125^{\circ}\text{C})$ | t _{rr} I _{RM} Q _{rr} S | 45 5.5 150 0.35 | - - - - | ns A nC - |
| Forward Recovery Time Peak Forward Recovery Voltage | $(I_F = 8 \text{ A}, d_{IF}/d_t = 120 \text{ A}/\mu\text{s}, T_C = 25^{\circ}\text{C})$ | t _{fr} V _{FP} | - | 200 6 | ns V |

^{2.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

NHPV08S600G

TYPICAL CHARACTERISTICS

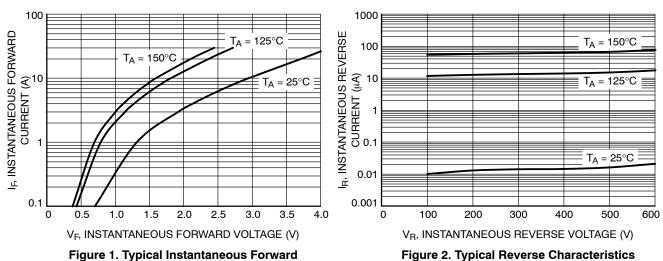


Figure 1. Typical Instantaneous Forward Characteristics

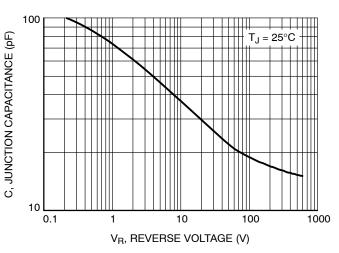


Figure 3. Typical Junction Capacitance

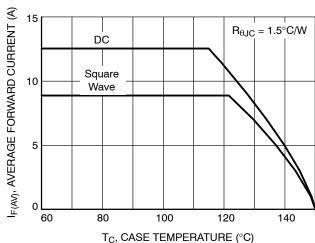


Figure 4. Current Derating TO-220AC

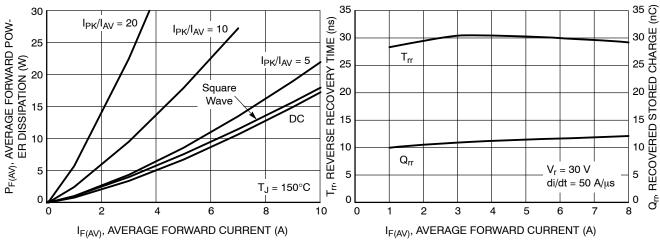


Figure 5. Forward Power Dissipation

Figure 6. Typical Recovery Characteristics





TO-220, 2-LEAD CASE 221B-04 **ISSUE F**

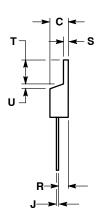
DATE 12 APR 2013

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

| | INC | HES | MILLIN | IETERS |
|-----|-------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.595 | 0.620 | 15.11 | 15.75 |
| В | 0.380 | 0.405 | 9.65 | 10.29 |
| С | 0.160 | 0.190 | 4.06 | 4.82 |
| D | 0.025 | 0.039 | 0.64 | 1.00 |
| F | 0.142 | 0.161 | 3.61 | 4.09 |
| G | 0.190 | 0.210 | 4.83 | 5.33 |
| Н | 0.110 | 0.130 | 2.79 | 3.30 |
| J | 0.014 | 0.025 | 0.36 | 0.64 |
| K | 0.500 | 0.562 | 12.70 | 14.27 |
| L | 0.045 | 0.060 | 1.14 | 1.52 |
| Q | 0.100 | 0.120 | 2.54 | 3.04 |
| R | 0.080 | 0.110 | 2.04 | 2.79 |
| S | 0.045 | 0.055 | 1.14 | 1.39 |
| T | 0.235 | 0.255 | 5.97 | 6.48 |
| U | 0.000 | 0.050 | 0.000 | 1.27 |

Q Н



STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE

PIN 1. ANODE 2. N/A 3. CATHODE 4. ANODE

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